## MM3722 series

## 概要 / OUTLINE

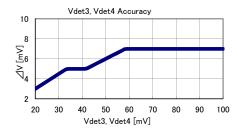
MM3722シリーズは電流検出抵抗Rsnsを用いることで充電/放電電流異常を高精度に検出可能なLiイオン/Liポリマー2次電池保護ICです。従来のLi-ion電池パックでは過電流・短 絡検出抵抗としてばらつきの大きなFET SWのON抵抗が使われてきました。MM3722シリーズでは外付けチップ抵抗を用いることにより過電流・短絡検出の高精度化と温度依存性 の向上を実現しています。

MM3722 series are Li-ion battery protection IC and detect charge current / discharge current with high precision by current sensing resistor (Rsns). In the One-cell battery pack, on resistance of the FET SW has been used for over-current/short-current detection. MM3722 realize over-current/short-current protection with high accuracy and with no temperature dependence by using a chip resistor.

## 特徵 / FEATURES

,検出電圧選択範囲と精度 / Range and accuracy of d	etection voltage		(特記なき場合、Ta=+25℃)
項目/Item	記号/SYMBOL	設定範囲/Range	精度/Accuracy
<ul><li>過充電検出電圧</li></ul>	Vdet1	3.6V to 5.0V	±20mV
Overcharge detection voltage		5mV step	$\pm 25$ mV (Ta=-20 to $+60$ °C)
<ul><li>過充電復帰電圧</li></ul>	Vrel1	Vdet1-0.2V to Vdet1	±30mV
Overcharge release voltage		5mV step	
・過放電検出電圧	Vdet2	2.0V to 3.0V	±35mV
Overdischarge detection voltage		50mV step	
• 過放電復帰電圧	Vrel2	2.0V to 3.0V	+65 / -35mV (In case Vdet2=Vrel2)
Overdischarge release voltage		50mV step	+90 / -65mV (In case Vdet2≠Vrel2)
<ul><li>放電過電流検出電圧</li></ul>	Vdet3	20mV to 150mV	±⊿V *1
Discharging overcurrent detection voltage		1mV step	
<ul><li>・充電過電流検出電圧</li></ul>	Vdet4	-20mV to -150mV	±⊿V *1
Charging overcurrent detection voltage		1mV step	
<ul><li>短絡検出電圧</li></ul>	Vshort	40mV to 250mV	±20%
Short detection voltage		1mV step	
・ 0V充電禁止電池電圧	Vst	1.3V to 1.8V / 0.1V step	±100mV
0V battery charge inhibition battery voltage		0.9V	±300mV

#### \*1 過電流検出精度/Current detection voltage Accuracy



## 2, 遅延時間の設定 / Delay time setting

	記号/SYMBOL	設定範囲/Range
<ul><li>過充電検出遅延時間</li></ul>	tVdet1	256ms to 4.6s
Overcharge detection delay time		
• 過放電検出遅延時間	tVdet2	8ms to 256ms
Overdischarge detection delay time		
<ul><li>放電過電流検出遅延時間</li></ul>	tVdet3	8ms to 256ms
Discharging overcurrent detection delay time		
<ul><li>充電過電流検出遅延時間</li></ul>	tVdet4	6ms to 64ms
Charging overcurrent detection delay time		
<ul><li>短絡検出遅延時間</li></ul>	tVshort	250us to 400us
Short detection delay time		

## 3, 低消費電流/Current consumption

通常動作モード時 Normal mode スタンバイモード時 Stand-by mode

Typ. 3.0uA, Max. 6.0uA

Max. 0.1uA (過放電ラッチ機能ありの場合 / In case Overdischarge latch function Enable.) Max 0.6uA (過放電ラッチ機能なしの場合 / In case Overdischarge latch function Disable.)

4, 0V電池への充電機能 0V battery Charge function

"許可"/"禁止"選択可能

VDD-28V to VDD+0.3V

VSS-0.3V to VDD+0.3V

VSS-0.3V to 12V

-55 to +125°C

-40 to +85°C

Selectable "Permission" or "inhibition"

#### 5, 絶対最大定格 / Absolute maximum ratings

・VDD端子 / VDD pin ・COUT端子、V-端子 / COUT pin and V- pin • DOUT端子、CS端子 / DOUT pin and CS pin

· 保存温度 / Storage temperature ・動作周囲温度 / Operation temperature

6, パッケージラインナップ/ PKG Line up SSON-6J SON-6C

\* 上記以外の仕様をご希望の場合は、弊社までお問い合わせください Please inquire to us, if you need another spec.

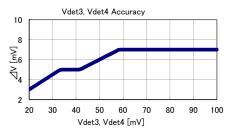
MITSUMI ELECTRIC Co.,LTD. Mar. '15

## 電気的特性 / ELECTRICAL CHARACTERISTICS

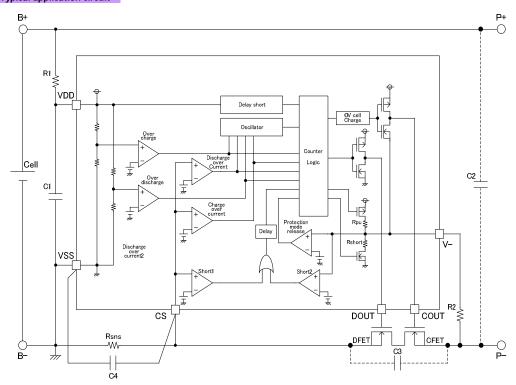
特記なき場合 Ta=25℃ / Ta=25℃, unless otherwise specified

項目/Item	単位/∐nit	記号/Symbol		台 Ta=25℃ / Ta= Min	Typ	otherwise specified Max
動作電圧			m为/Note		175	
Operating voltage	V	Vop		1.5	-	5.5
動作周囲温度	0-	_				0.5
Operating Ambient temperature	°C	Та		-40	-	85
過電流復帰抵抗	lankana.	Debest	VDD 3.6V.65 0V.V. 3.0V	D-1+*0 C	Debest	D-b+*2.0
Discharge overcurrent release resistance	kohms	Rshort	VDD=3.6V, CS=0V, V-=2.0V	Rshort*0.6	Rshort	Rshort*2.0
V-端子プルアップ抵抗	kohms	Rpu	VDD=2.0V, CS=V-=0V	Rpu*0.5	Rpu	Rpu*2.0
V- terminal pull-up resistances	KOHITIS	кри	VDD=2.0V, CS=V-=0V	кри о.5	кри	кри - 2.0
COUT Lレベル出力電圧	V	VcoL	Icout=30uA, VDD=4.5V	_	0.1	0.5
COUT L level output voltage	·	VCOL	100t-30th y 100-1131		0.1	0.5
COUT Hレベル出力電圧	V	VcoH	Icout=-30uA, VDD=4.0V	VDD-0.5	VDD-0.1	-
COUT H level output voltage			,			
DOUT Lレベル出力電圧	V	VdoL	Idout=30uA, VDD=2.0V	-	0.1	0.5
DOUT L. evel output voltage						
DOUT Hレベル出力電圧 DOUT H level output voltage	V	VdoH	Idout=-30uA, VDD=4.0V	VDD-0.5	VDD-0.1	-
消費電流						
Current consumption	uA	Idd	VDD=4.0V, V-=CS=0V	-	3.0	6.0
スタンバイ電流			VDD=2.0V, CS=0V			
Current consumption at stand-by			*3	-	-	0.1
carrone consumption at stanta sy	uA	Is	VDD=2.0V, CS=0V			
			*4	-	0.3	0.6
0V充電許可充電器電圧	.,,		Vst=VDD-V-, VDD=CS=0V			1.2
0V battery charge permission charger voltage	V	Vst	*1	-	-	1.2
0V充電禁止電池電圧	V	VSL	Vst=VDD-VSS, V-=CS=0V	Vst-0.1	Vst	Vst+0.1
0V battery charge inhibition battery voltage	V		*2	VSC-0.1	VSC	VS(+0.1
過充電検出電圧	V	Vdet1	Ta=25°C V-=CS=0V	Vdet1-0.020	Vdet1	Vde1+0.020
Overcharge detection voltage	·	74662	Ta=-20 to 60°C V-=CS=0V	Vdet1-0.025	70012	Vde1+0.025
過充電復帰電圧	V	Vrel1	*5	Vrel1-0.030	Vrel1	Vrel1+0.030
Overcharge release voltage		_	-			
過放電検出電圧	V	Vdet2	V-=CS=0V	Vdet1-0.035	Vdet2	Vde1+0.035
Overdischarge detection voltage 過放電復帰電圧						
廻放电接滞电圧 Overdischarge release voltage			In case Vdet2=Vrel2 *3 *5	Vrel2-0.035		Vrel2+0.065
Overdischarge release voltage	V	Vrel2			Vrel2	
			In case Vdet2≠Vrel2 *4 *5	Vdet1-0.065		Vdet1+0.090
放電過電流検出電圧						
Discharging overcurrent detection voltage	V	Vdet3	VDD=3.6V, V-=0V *6	Vdet3-⊿V	Vdet3	Vdet3+⊿V
充電過電流検出電圧	V	\/dat4	VDD 2 CV V 0V *C	\/dat4	\/dat4	\/dat4 \ 4\/
Charging overcurrent detection voltage	V	Vdet4	VDD=3.6V, V-=0V *6	Vdet4-⊿V	Vdet4	Vdet4+⊿V
短絡検出電圧	V	Vshort	VDD=3.6V, V-=0V	Vshort-20%	Vshort	Vshort+20%
Short detection voltage	V	VOLIUIT	ייט - טיט V, VUV	V 51 101 L-20%	VSHULL	VSHULT-2070
過充電検出遅延時間	ms	tVdet1		tVdet1*0.8	tVdet1	tVdet1*1.2
Overcharge detection delay time	1113	LVUCLI		tvucti 0.0	LANCET	tvucti 1.2
過放電検出遅延時間	ms	tVdet2		tVdet2*0.8	tVdet2	tVdet2*1.2
Overdischarge detection delay time						
放電過電流検出遅延時間	ms	tVdet3		tVdet3*0.8	tVdet3	tVdet3*1.2
Discharging overcurrent detection delay time						
充電過電流検出遅延時間	ms	tVdet4		tVdet4*0.8	tVdet4	tVdet4*1.2
Charging overcurrent detection delay time						
短絡検出遅延時間	us	tVshort		tVshort*0.8	tVshort	tVshort*1.2
Short detection delay time						

- \*1 0V電池への充電機能"許可"の場合/In case 0V battery charge function "Permission".
- \*2 0V電池への充電機能"禁止"の場合/In case 0V battery charge function "inhibition".
- \*3 過放電ラッチ機能"あり"の場合/Overdischarge mode latch function "Enable".
- \*4 過放電ラッチ機能"なし"の場合/Overdischarge mode latch function "Disable".
  \*5 復帰条件は各ランクの仕様書を参照ください./Please refer to each specifications for release condition.
- \*6 過電流検出精度/Current detection voltage Accuracy



## 応用回路例 / Typical application circuit

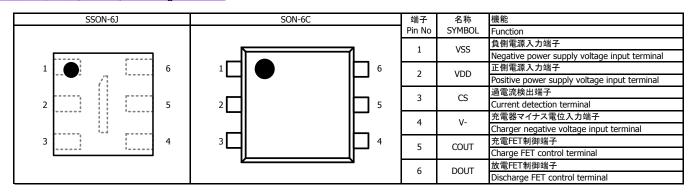


記号	品略	最小値		最大値	目的
Symboli	Part	Min.	Typ.	Max.	Purpose
R1	Resistor	-	100	1ΚΩ	電源電圧変動対策、ESD対策 For voltage fluctuation, For ESD
C1	Capacitor	0.01uF 0.1uF		1.0uF	電源電圧変動対策 For voltage fluctuation
R2	Resistor	-	1.0kΩ	10kΩ	充電器逆接電流制限 Current limit for charger reverse connection
C2	Capacitor	-	0.1uF	-	ノイズ対策 For exogenous noise
C3	Capacitor	itor - 0.1uF		-	ノイズ対策 For exogenous noise
Rsns	Resistor	-	-	20mΩ	電流検出抵抗 Current detection resistance
C4	Capacitor	-	0.1uF	-	ノイズ対策 For exogenous noise
DFET CFET	Nch MOS FET	-	-	-	充放電制御 Charge and discharge control

<sup>\*</sup> 本回路例および定数は、動作を保証するものではありません。実際のアプリケーションで十分な評価を実施の上、定数を設定してください。

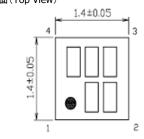
This typical application circuit and constant value do not guarantee proper operation. Please evaluate thoroughly by actual application to set up constants.

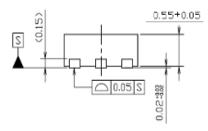
## パッケージ、ピン配置 / PKG, Pin configuration

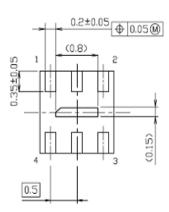


## パッケージ外形図 / PACKAGE DIMENSIONS

## SSON-6J 表面(Top View)



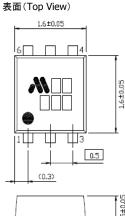


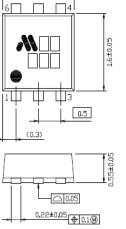




、 1ピンマーク(1-Pin Mark)

# SON-6C

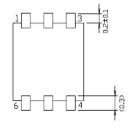




UNIT: mm

0.13±0.05

2,0±0,1



## マーク内容(Marking Contents)/S0N-6C





## 製品ラインナップ / LINE UP

機種名 MODEL	パッケー・ PKG	/充電禁 e prohil	保護状態ラッチファンクション Protection mode latch function			ヒスキャンセル Hys-Cancel #		広大機能 t release ction.	出電圧 detection ge			電压 release	検出電圧 wercurrent voltage	後出電圧 /ercurrent voltage	田田	/ time *1	nt state
			過充電 Overcharge	過放電 Overdischarge	放電過電流 arge overcurrent		過放電 Overdischarge	電流復帰範囲射 ging overcurren e extended fun	過充電検出電圧 Overcharge detect voltage	vercharge ( voltag 過充電復 Jvercharge	過放電検出 Overdischarge d voltage	過放電復帰電圧 Overdischarge relea voltage	放電過電流検出電圧 Discharging overcurre detection voltage	充電過電流検出電圧 Charging overcurrer detection voltage	短絡検出電 Short detection	遅延時間/ Delay	発状況/Development
		0 00			0	放電 Discharge		0	放電過 <sup>;</sup> Discharg rang	Vdet1 [V]	Vrel1 [V]	Vdet2 [V]	Vrel2 [V]	Vdet3 [V]	Vdet4 [V]	Vshort [V]	-
MM3722AJ1YRE	SON-6C	Permission	Disable	Disable	Disable	Enable	Enable	Yes(VDD-0.9V)	4.425	4.225	2.500	2.900	0.036	-0.020	0.060	В	ES
MM3722AM1RRE	SSON-6J	0.9	Disable	Disable	Disable	Enable	Enable	Yes(VDD-0.9V)	4.475	4.275	2.500	2.900	0.032	-0.020	0.060	В	ES
MM3722KF1RRE	SSON-6J	0.9	Enable	Enable	Disable	-	-	Yes(1.0V)	4.280	4.280	2.400	2.400	0.032	-0.030	0.180	Α	MP
MM3722KF2RRE	SSON-6J	0.9	Enable	Enable	Disable	-	-	Yes(1.0V)	4.425	4.425	2.400	2.400	0.034	-0.022	0.180	Α	MP
MM3722KF3RRE	SSON-6J	0.9	Enable	Enable	Disable	-	-	Yes(1.0V)	4.425	4.425	2.800	2.800	0.040	-0.030	0.180	Α	ES
MM3722KF4RRE	SSON-6J	1.5	Enable	Enable	Disable	-	-	Yes(1.0V)	4.425	4.425	2.600	2.600	0.040	-0.030	0.180	Α	ES

## \*1 遅延時間/Delay time

	tVdet1 [s]	tVrel1 [ms]	tVdet2 [ms]	tVrel2 [ms]	tVdet3 [ms]	tVrel3 [ms]	tVdet4 [ms]	tVrel4 [ms]	tshort [us]
Α	1.000	16.00	20.00	1.00	12.00	1.00	16.00	1.00	250
В	1.024	16.00	96.00	1.00	12.00	1.00	10.00	1.00	300

\* 上記以外の仕様をご希望の場合は、弊社までお問い合わせください Please inquire to us, if you need another spec.